



D4V5H1U2LP1610Q

ONE CHANNEL HIGH SURGE TVS DIODE

Product Summary

V _{BR} (Min)	IPP (Max)	Ст (Тур)
5.5V	90A	800pF

Features

- Provides ESD Protection per IEC 61000-4-2 Standard: Air ±30kV, Contact ±30kV
- One Channel of ESD Protection
- Low Channel Input Capacitance

Mechanical Data

•

Package: U-DFN1610-2

- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The D4V5H1U2LP1610Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Package Material: Molded Plastic, "Green" Molding Compound.

UL Flammability Classification Rating 94V-0 Moisture Sensitivity: Level 1 per J-STD-020

Terminals: NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @

Weight: 0.003 grams (Approximate)

Description

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for protecting one line against high surge current and other transients. These robust diodes can safely absorb repetitive ESD strikes at ± 30 kV without performance degradation. Additionally, it can safely dissipate 90A of 8/20µs surge current (IEC 61000-4-5) with very low clamping voltages.

Applications

- Power line protections
- Touch panels

Notes:

Small panel modules

U-DFN1610-2 (Type B)







Device Schematic

Ordering Information (Note 4)

Part Number	Baakaga	Marking	Reel Size (inches)	Tape Width (mm)	Pac	Packing	
Part Number	Package	Warking	Reel Size (inches)	Tape width (mm)	Qty.	Carrier	
D4V5H1U2LP1610Q-7	U-DFN1610-2 (Type B)	MW2	7	8	10,000	Tape & Reel	

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Option A:



MW2 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: K = 2023) M = Month (ex: 9 = September)

Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	K	L	М	Ν	Р	R	S	Т	U	V	W	Х
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	٥	0	Ν	П

Option B:

	MW2
	YWX
•	

MW2 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	3	4	5	6	7	8	9	0	1	2	3	4
Week	1-26			27-52				53				
Code	A-Z				a-z			Z				
Internal Code	Sur	Sun Mon		Tue	W	ed	Thu		Fri		Sat	
Code	Т		U		V	V	V	Х		Y		Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current	IPP	90	A	8/20µs (Note 5)
ESD Protection – Contact Discharge	Vesd_contact	±30	kV	Standard IEC 61000-4-2
ESD Protection – Air Discharge	Vesd_air	±30	kV	Standard IEC 61000-4-2
ESD Protection – 1000 Contact Discharges (Open Alliance Spec)	Vesd_contact1k	±30	kV	Standard IEC 61000-4-2
ESD Protection – Contact Discharge (ISO Spec)	Vesd_contact2	±30	kV	ISO 10605, 150pF, 330Ω
ESD Protection – Air Discharge (ISO Spec)	Vesd_air2	±30	kV	ISO 10605, 150pF, 330Ω
ESD Protection – Contact Discharge (ISO Spec)	Vesd_contact3	±30	kV	ISO 10605, 330pF, 330Ω
ESD Protection – Air Discharge (ISO Spec)	V _{ESD_AIR3}	±30	kV	IEC 10605, 330pF, 330Ω

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	500	mW
Thermal Resistance, Junction to Ambient, $T_A = +25^{\circ}C$	Reja	250	°C/W
Operating and Storage Temperature Range	TJ, T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	VRWM	_	—	4.5	V	—
Channel Leakage Current (Note 7)	IR	_	—	1.0	μA	V _R = 4.5V
Reverse Breakdown Voltage	VBR	5.5	—	8	V	I _R = 1mA
		_	—	10	V	IPP = 10A, tP = 8/20µs
Clamping Voltage, Positive Transients (Note 5)	Vc	_	_	11	V	IPP = 50A, tP = 8/20µs
(1000 5)		_	_	13	V	IPP = 90A, tP = 8/20µs
Channel Input Capacitance (Note 8)	Ст	—	800	—	pF	$V_R = 0V$, f = 1MHz, Any I/O to GND
Dynamic Resistance	R _{DYN}	—	0.05	—	Ω	TLP, 10A, t _P = 100ns

Notes:

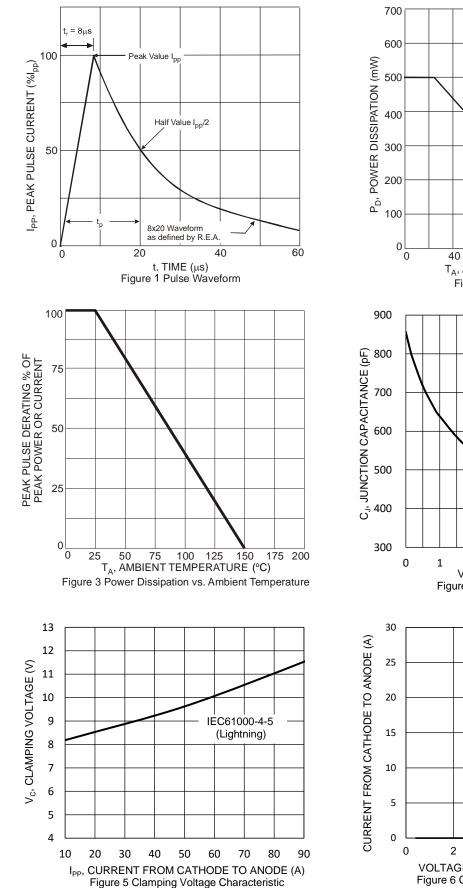
5. Clamping voltage value is based on an 8 x 20µs peak pulse current (l_{pp}) waveform.
6. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.
7. Short duration pulse test used to minimize self-heating effect.
9. More ward for my use to CNP

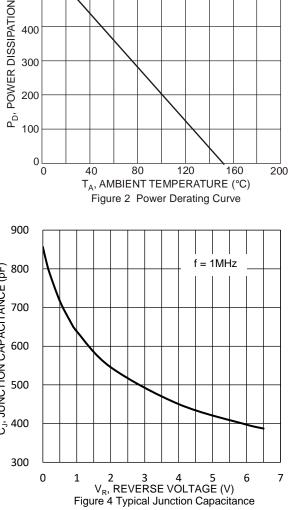
8. Measured from any I/O to GND.

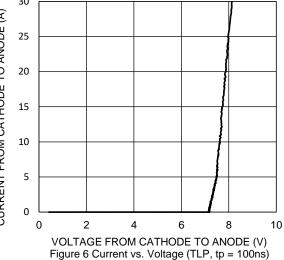
D4V5H1U2LP1610Q

Note 6





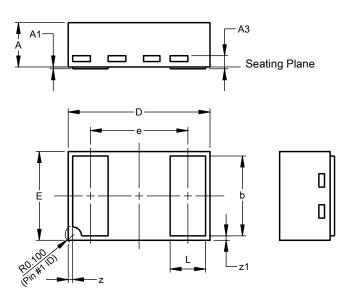






Package Outline Dimensions

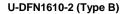
Please see http://www.diodes.com/package-outlines.html for the latest version.



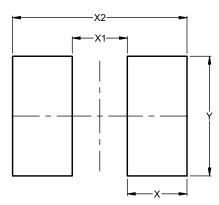
	U-DFN1610-2 (Type B)							
Dim	Min							
Α	0.45	0.55	0.50					
A1	0.00	0.05	0.015					
A3	-	-	0.127					
b	0.85	0.95	0.90					
D	1.55	1.65	1.60					
E	0.95	1.05	1.00					
е	-	-	1.10					
L	0.35 0.45 0.40							
z	0.050 REF							
z1	(0.050 REF						
All D	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



U-DFN1610-2 (Type B)



Dimensions	Value
Dimensions	(in mm)
Х	0.650
X1	0.600
X2	1.900
Y	1.300



IMPORTANT NOTICE

1. DIODES INCORPORATED (Diodes) AND ITS SUBSIDIARIES MAKE NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO ANY INFORMATION CONTAINED IN THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

2. The Information contained herein is for informational purpose only and is provided only to illustrate the operation of Diodes' products described herein and application examples. Diodes does not assume any liability arising out of the application or use of this document or any product described herein. This document is intended for skilled and technically trained engineering customers and users who design with Diodes' products. Diodes' products may be used to facilitate safety-related applications; however, in all instances customers and users are responsible for (a) selecting the appropriate Diodes products for their applications, (b) evaluating the suitability of Diodes' products for their intended applications, (c) ensuring their applications, which incorporate Diodes' products, comply the applicable legal and regulatory requirements as well as safety and functional-safety related standards, and (d) ensuring they design with appropriate safeguards (including testing, validation, quality control techniques, redundancy, malfunction prevention, and appropriate treatment for aging degradation) to minimize the risks associated with their applications.

3. Diodes assumes no liability for any application-related information, support, assistance or feedback that may be provided by Diodes from time to time. Any customer or user of this document or products described herein will assume all risks and liabilities associated with such use, and will hold Diodes and all companies whose products are represented herein or on Diodes' websites, harmless against all damages and liabilities.

4. Products described herein may be covered by one or more United States, international or foreign patents and pending patent applications. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks and trademark applications. Diodes does not convey any license under any of its intellectual property rights or the rights of any third parties (including third parties whose products and services may be described in this document or on Diodes' website) under this document.

5 Diodes' products are provided subject to Diodes' Standard Terms and Conditions of Sale (https://www.diodes.com/about/company/terms-and-conditions/terms-and-conditions-of-sales/) or other applicable terms. This document does not alter or expand the applicable warranties provided by Diodes. Diodes does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

6. Diodes' products and technology may not be used for or incorporated into any products or systems whose manufacture, use or sale is prohibited under any applicable laws and regulations. Should customers or users use Diodes' products in contravention of any applicable laws or regulations, or for any unintended or unauthorized application, customers and users will (a) be solely responsible for any damages, losses or penalties arising in connection therewith or as a result thereof, and (b) indemnify and hold Diodes and its representatives and agents harmless against any and all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim relating to any noncompliance with the applicable laws and regulations, as well as any unintended or unauthorized application.

7. While efforts have been made to ensure the information contained in this document is accurate, complete and current, it may contain technical inaccuracies, omissions and typographical errors. Diodes does not warrant that information contained in this document is error-free and Diodes is under no obligation to update or otherwise correct this information. Notwithstanding the foregoing, Diodes reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes.

8. Any unauthorized copying, modification, distribution, transmission, display or other use of this document (or any portion hereof) is prohibited. Diodes assumes no responsibility for any losses incurred by the customers or users or any third parties arising from any such unauthorized use.

9. This Notice may be periodically updated with the most recent version available at https://www.diodes.com/about/company/terms-and-conditions/important-notice

The Diodes logo is a registered trademark of Diodes Incorporated in the United States and other countries. All other trademarks are the property of their respective owners. © 2023 Diodes Incorporated. All Rights Reserved.

www.diodes.com